



74LV04A HEX INVERTERS

Description

The 74LV04A provides provides six independent inverters with standard push-pull outputs. The device is designed for operation with a power supply range of 2.0V to 5.5V.

The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

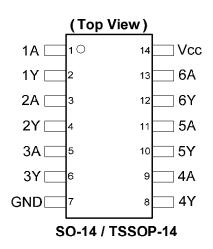
The gates perform the Boolean function:

 $Y = \overline{A}$

Features

- Wide Supply Voltage Range from 2.0V to 5.5V
- Sinks or sources 12mA at V_{CC} = 4.5V
- CMOS low power consumption
- I_{OFF} Supports Partial -Power Down Operation
- Inputs or Outputs accept up to 5.5V
- Inputs can be driven by 3.3V or 5V allowing for voltage translation applications.
- Schmitt Trigger Action at All Inputs
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115)
 - Exceeds 2000-V Human Body Model (A114)
 - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as:
 - PCs, networking, notebooks, ultrabooks, netbooks
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top box

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

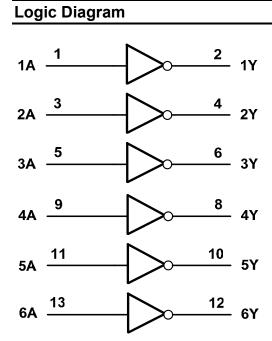
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Click here for ordering information, located at the end of datasheet



Pin Descriptions

Pin Number	Pin Name	Description
1	1A	Data Input
2	1Y	Data Output
3	2A	Data Input
4	2Y	Data Output
5	3A	Data Input
6	3Y	Data Output
7	GND	Ground
8	4Y	Data Output
9	4A	Data Input
10	5Y	Data Output
11	5A	Data Input
12	6Y	Data Output
13	6A	Data Input
14	Vcc	Supply Voltage



Function Table

Input	Output
Α	Y
Н	L
L	Н

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range (Note 4)	-0.5 to +7.0	V
lıĸ	Input Clamp Current VI< 0V	-20	mA
Ι _{ΟΚ}	Output Clamp Current V _O <-0V	-50	mA
lo	Continuous Output Current - 0.5V < V _O Vcc + 0.5V	±25	mA
Icc	Continuous Current Through Vcc	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage		2.0	5.5	V
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	Vcc	V
		2.0V		-50	mA
	High-Level Output Current	2.3V to 2.7V		-2	μA
I _{ОН}		3.0V to 3.6V		-6	mA
		4.5V to 5.5V		-12	mA
		2.0V		50	μA
	Low-Level Output Current	2.3V to 2.7V		2	mA
I _{OL}	Low-Level Output Current	3.0V to 3.6V		6	mA
		4.5V to 5.5V		12	mA
		2.3V to 2.7V		200	
Δt/ΔV	Input Transition Rise or Fall	3.0V to 3.6V		100	ns/V
Trate		4.5V to 5.5V		20	
T _A	Operating Free-Air Temperature		-40	125	°C

Note: 5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Sympol	Devemeter	Test Conditions	Maa	T _A = -40°C	C to +85°C	T _A = -40°C	to +125°C	l lmit
Symbol	Parameter	Test Conditions	Vcc	Min	Max	Min	Max	Unit
			2.0V	1.5		1.5		
Ň	High-Level Input		2.3V to 2.7V	V _{CC} X 0.7		V _{CC} X 0.7		V
VIH	Voltage		3.0V to 3.6V	V _{CC} X 0.7		V _{CC} X 0.7		
			4.5V to 5.5V	V _{CC} X 0.7		V _{CC} X 0.7		
			2.0V		0.5		0.5	
	Low-Level Input		2.3V to 2.7V		V _{CC} X 0.3		V _{CC} X 0.3	V
VIL	Voltage		3.0V to 3.6V		V _{CC} X 0.3		V _{CC} X 0.3	
			4.5V to 5.5V		V _{CC} X 0.3		V _{CC} X 0.3	
		I _{OH} = -50μA	2.0V to 5.5V	V _{CC} -0.1		V _{CC} -0.1		
.,	High-Level	I _{OH} = -2mA	2.3V	2.0		2.0		
V _{OH}	Output Voltage	I _{OH} = -6mA	3.0V	2.48		2.48		V
		I _{OH} = -12mA	4.5V	3.8		3.8		
		I _{OL} = 50μΑ	2.0V to 5.5V		0.1		0.1	
.,	Low-Level	I _{OL} = 2mA	2.3V		0.4		0.4	.,
V _{OL}	Output Voltage	I _{OL} = 6mA	3.0V		0.44		0.44	V
		I _{OL} = 12mA	4.5V		0.55		0.55	
I _{OFF}	Power Down Leakage Current	V_1 or V_0 = 0 to 5.5V	0V		5		5	μA
lı –	Input Current	V _I =GND or 5.5V	0 to 5.5V		±1		±1	μA
Icc	Supply Current	$V_1 = GND \text{ or } V_{CC}$ $I_0=0$	5.5V		20		20	μA



Switching Characteristics

Symbol	Parameter	Test	V	-	Γ _A = +25°C	;	-40°C to	o +85 °C	-40°C to	+125°C	Unit
Symbol	Conditio	Conditions	V _{cc}	Min	Тур	Max	Min	Max	Min	Max	Unit
		Figure 1	2.5V ± 0.2V	_	7.1	11.7	1	14	1	14	
		Figure 1 C _L = 15pF	3.3V ± 0.3V	_	5.1	7.1	1	8.5	1	8.5	ns
	Propagation	CL - Tope	5.0V ± 0.5V		3.6	5.5	1	6.5	1	6.5	
t _{PD}	Delay A _N to Y _N		2.5V ± 0.2V		10	15.5	1	18	1	18	
		Figure 1 C _I = 50 pF	3.3V ± 0.3V	_	7.3	10.6	1	12	1	12	ns
		0L - 00 pi	5.0V ± 0.5V		5.1	7.5	1	8.5	1	8.5	

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

	Parameter	Test Conditions	Vcc	Тур	Unit
0	Power Dissipation	F = 10 MHz	3.3V	9.6	~ C
C _{pd}	Capacitance per Gate	$C_L = 50 pF$	5.0V	11.4	pF

Noise Characteristics

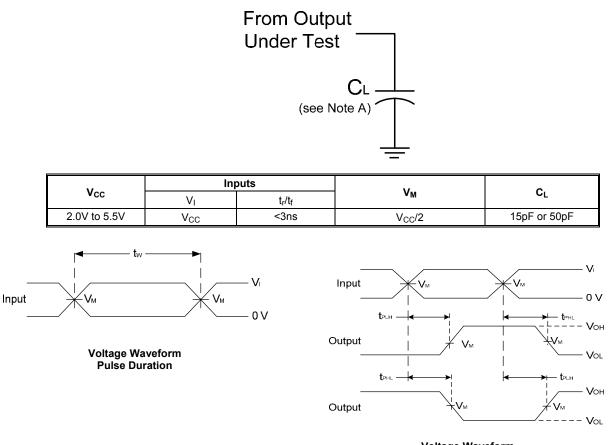
V_{CC} = 3V, C_{L} = 3	50pF T _A = +25°C				
Symbol	Parameter	Min	Тур	Max	Unit
V _{OL(p)}	Quiet output, maximum dynamic V _{OL}	—	0.2	0.8	V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}	_	-0.1	-0.8	V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}	_	3.1	—	V
V _{IH(D)}	High Level dynamic input voltage	2.31	_	_	V
V _{IL(D)}	Low Level dynamic input voltage	_	_	0.99	V

Package Characterisitics

Symbol	Parameter	Test Conditions	Vcc	Min	Тур	Max	Unit
Ci	Input Capacitance	$V_i = V_{CC} - or GND$	2.0 to 5.5V		3.3	10	pF



Parameter Measurement Information



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate \leq 10MHz. C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{PD}

Figure 1 Load Circuit and Voltage Waveforms



13" Tape and Reel

Quantity

2500/Tape & Reel

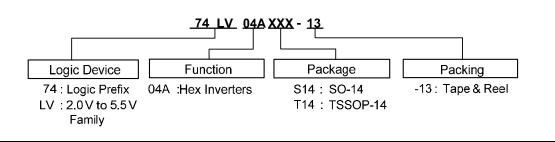
2500/Tape & Reel

Part Number Suffix

-13

-13

Ordering Information



Note: 6. The taping orientation and tape details can be found at http://www.diodes.com/datasheets/ap02007.pdf

Package Code

S14

T14

Packaging

(Note 6)

SO-14

TSSOP-14

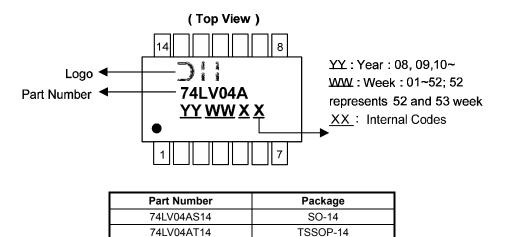
Marking Information

Device

74LV04AS14-13

74LV04AT14-13

(1) SO14, TSSOP14

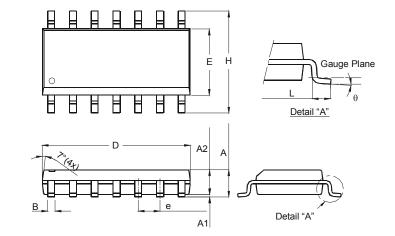




Package Outline Dimensions (All dimensions in mm.)

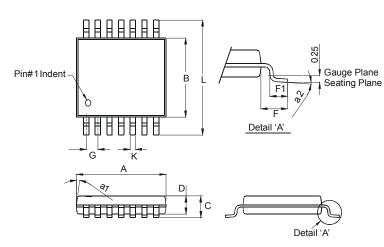
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



	SO-14				
Dim	Min	Max			
Α	1.47	1.73			
A1	0.10	0.25			
A2	1.45	Тур			
В	0.33	0.51			
D	8.53	8.74			
E	3.80	3.99			
е	1.27	Тур			
н	5.80	6.20			
L	0.38	1.27			
θ	0°	8°			
All Di	mensions	s in mm			

Package Type: TSSOP-14



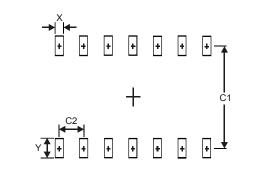
	TSSOP-1	4	
Dim	Min	Max	
a1	7° (4X)	
a2	0°	8°	
Α	4.9	5.10	
в	4.30	4.50	
С	_	1.2	
D	0.8	1.05	
F	1.00	Тур	
F1	0.45	0.75	
G	0.65	Тур	
κ	0.19	0.30	
L	6.40 Typ		
All Dir	nensions	s in mm	



Suggested Pad Layout

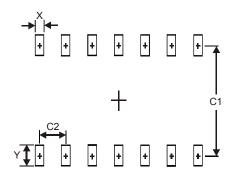
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



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